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74LVTN16244B 3.3 V 16-bit buffer/driver; 3-state Rev. 5 — 2 April 2012

Product data sheet

1. **General description**

The 74LVTN16244B is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V.

This device is a 16-bit buffer and line driver featuring non-inverting 3-state bus outputs. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

Features and benefits 2.

- 16-bit bus interface
- 3-state buffers
- Output capability: +64 mA and -32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Power-up 3-state
- Live insertion and extraction permitted
- No bus current loading when output is tied to 5 V bus
- Latch-up protection
 - JESD78B Class II exceeds 500 mA
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V

Ordering information 3.

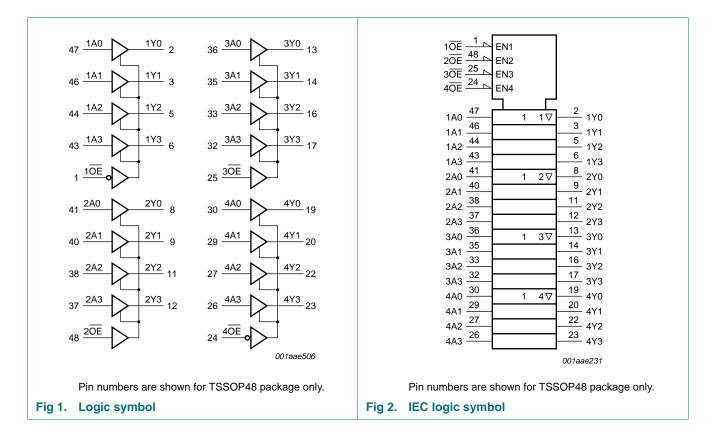
Ordering information Table 1.

Type number	Package			
	Temperature range	Name	Description	Version
74LVTN16244BDGG	–40 °C to +85 °C	TSSOP48	plastic thin shrink small outline package; 48 leads; body width 6.1 mm	SOT362-1
74LVTN16244BBX	–40 °C to +125 °C	HXQFN60	plastic compatible thermal enhanced extremely thin quad flat package; no leads; 60 terminals; body $4 \times 6 \times 0.5$ mm	SOT1134-2



3.3 V 16-bit buffer/driver; 3-state

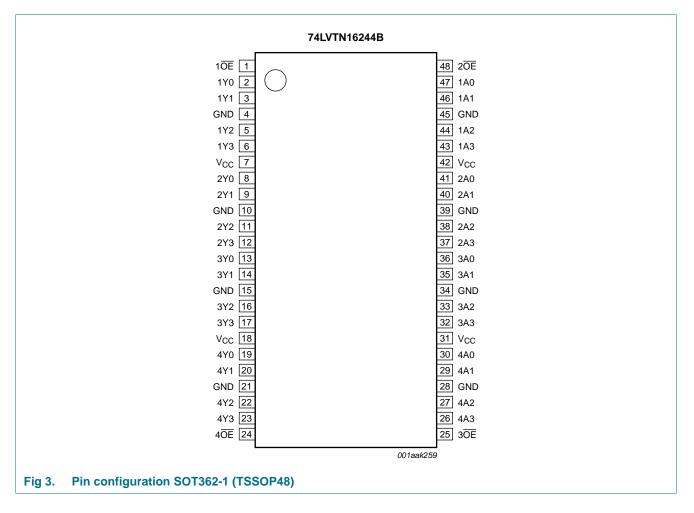
4. Functional diagram





5. Pinning information

5.1 Pinning



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74LVTN16244B

3.3 V 16-bit buffer/driver; 3-state

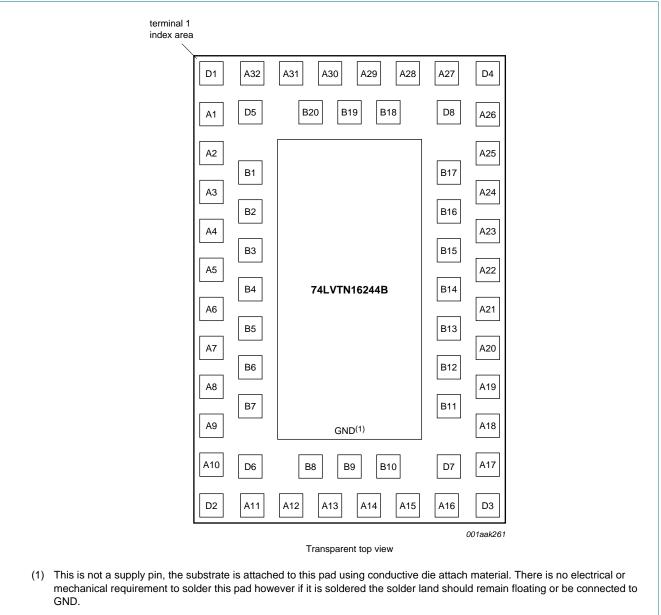


Fig 4. Pin configuration SOT1134-2 (HXQFN60)

5.2 Pin description

Symbol	Pin		Description	
	SOT362-1	SOT1134-2	·	
1 <u>0E</u> , 2 <u>0E,</u> 30E, 40E	1, 48, 25, 24	A30, A29, A14, A13	output enable input	(active LOW)
1Y0 to 1Y3	2, 3, 5, 6	B20, A31, D5, D1	data output	
2Y0 to 2Y3	8, 9, 11, 12	A2, B2, B3, A5	data output	
3Y0 to 3Y3	13, 14, 16, 17	A6, B5, B6, A9	data output	
4Y0 to 4Y3	19, 20, 22, 23	D2, D6, A12, B8	data output	
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Product data sheet

3.3 V 16-bit buffer/driver; 3-state

SOT362-1 SOT1134-2 GND 4, 10, 15, 21, 28, 34, 39, A32, A3, A8, A11, A16, A1	9, ground (0 V)
GND 4, 10, 15, 21, 28, 34, 39, A32, A3, A8, A11, A16, A1	9, ground (0 V)
45 A24, A27	
V _{CC} 7, 18, 31, 42 A1, A10, A17, A26	supply voltage
1A0 to 1A3 47, 46, 44, 43 B18, A28, D8, D4	data input
2A0 to 2A3 41, 40, 38, 37 A25, B16, B15, A22	data input
3A0 to 3A3 36, 35, 33, 32 A21, B13, B12, A18	data input
4A0 to 4A3 30, 29, 27, 26 D3, D7, A15, B10	data input
n.c A4, A7, A20, A23, B1, B4, B9, B11, B14, B17, B19	B7, not connected

Table 2 Pin description continued

6. Functional description

Input	Output
nAn	nYn
L	L
Н	Н
Х	Z
	nAn L

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Limiting values 7.

Limiting values Table 4.

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

		0, () 0		10	,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage		<u>[1]</u> –0.5	+7.0	V
Vo	output voltage	output in OFF-state or HIGH-state	[1] -0.5	+7.0	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
lo	output current	output in LOW-state	-	128	mA
		output in HIGH-state	-64	-	mA
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		[2] _	150	°C

3.3 V 16-bit buffer/driver; 3-state

Table 4. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					-
Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +85 \ ^{\circ}C;$			
		TSSOP48 package	[3] _	500	mW
		HXQFN60 package	[4] _	1000	mW

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

[3] Above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.

[4] Above 70 °C the value of P_{tot} derates linearly with 1.8 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		2.7	-	3.6	V
VI	input voltage		0	-	5.5	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.8	V
I _{OH}	HIGH-level output current		-32	-	-	mA
I _{OL}	LOW-level output current	none	-	-	32	mA
		$\begin{array}{l} \mbox{current duty cycle} \leq 50 \ \%; \\ f_i \geq 1 \ \mbox{kHz} \end{array}$	-	-	64	mA
T _{amb}	ambient temperature	in free-air	-40	-	+85	°C
$\Delta t / \Delta V$	input transition rise and fall rate	outputs enabled	-	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} =	40 °C to +85 °C <u>^[1]</u>					
V _{IK}	input clamping voltage	V_{CC} = 2.7 V; I _{IK} = -18 mA	-1.2	-0.85	-	V
V _{OH}	HIGH-level output voltage	I_{OH} = $-100~\mu\text{A};~V_{CC}$ = 2.7 V to 3.6 V	$V_{CC}-0.2$	V _{CC}	-	V
		$I_{OH} = -8 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.4	2.5	-	V
		$I_{OH} = -32 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.0	2.3	-	V
V _{OL}	LOW-level output voltage	$V_{CC} = 2.7 V$				
		I _{OL} = 100 μA	-	0.07	0.2	V
		I _{OL} = 24 mA	-	0.3	0.5	V
		V _{CC} = 3.0 V				
		I _{OL} = 16 mA	-	0.25	0.4	V
		I _{OL} = 32 mA	-	0.3	0.5	V
		I _{OL} = 64 mA	-	0.4	0.55	V
I	input leakage current	all input pins; V_{CC} = 0 V or 3.6 V; V_{I} = 5.5 V	-	0.1	10	μΑ
		control pins; V_{CC} = 3.6 V; V_I = V_{CC} or GND	-	0.1	±1.0	μΑ
		data pins; unused pins at V_{CC} or GND				
		$V_{I} = V_{CC}; V_{CC} = 3.6 V$	-	0.1	1	μA
		$V_{I} = 0 V; V_{CC} = 3.6 V$	-5	-0.1	-	μA
I _{OFF}	power-off leakage current	V_{CC} = 0 V; V ₁ or V ₀ = 0 V to 4.5 V	-	0.1	±100	μΑ
I _{LO}	output leakage current	output in HIGH-state when V _O > V _{CC} ; V _O = 5.5 V; V _{CC} = 3.0 V	-	50	125	μΑ
I _{O(pu/pd)}	power-up/power-down output current	$V_{CC} \leq \underline{1.2} \text{ V}; \text{V}_{O} = 0.5 \text{ V} \text{ to } \text{V}_{CC}; \text{V}_{I} = \text{GND or } \text{V}_{CC}; \text{ nOE} = \text{don't care}$	[2] _	1	±100	μΑ
l _{oz}	OFF-state output current	V_{CC} = 3.6 V; V_{I} = V_{IH} or V_{IL}				
		output HIGH: $V_0 = 3.0 V$	-	0.5	5	μA
		output LOW: $V_0 = 0.5 V$	-5	+0.5	-	μA
I _{CC}	supply current	V_{CC} = 3.6 V; V_{I} = GND or V_{CC} ; I_{O} = 0 A				
		output HIGH	-	0.07	0.12	mA
		output LOW	-	4.0	6.0	mA
		outputs disabled	[3]	0.07	0.12	mA
ΔI_{CC}	additional supply current	per input pin; V _{CC} = 3.0 V to 3.6 V; one input at V _{CC} – 0.6 V other inputs at V _{CC} or GND	<u>[4]</u> -	0.1	0.2	mA
CI	input capacitance	V _I = 0 V or 3.0 V	-	3	-	pF
Co	output capacitance	outputs disabled; $V_0 = 0 V \text{ or } 3.0 V$	-	9	-	pF

[1] Typical values are measured at V_{CC} = 3.3 V and at T_{amb} = 25 °C.

[2] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From V_{CC} = 1.2 V to V_{CC} = 3.3 V \pm 0.3 V a transition time of 100 μ s is permitted. This parameter is valid for T_{amb} = 25 °C only.

[3] ~~ I_{CC} is measured with outputs pulled to V_{CC} or GND.

[4] This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

10. Dynamic characteristics

Table 7. Dynamic characteristics

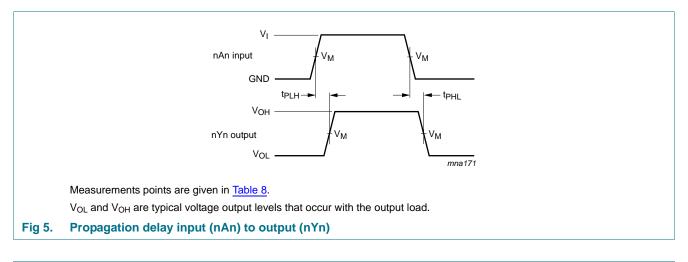
Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 7</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -40) ℃ to +85 ℃ <u>[1]</u>					
t _{PLH}	LOW to HIGH	nAn to nYn; see <u>Figure 5</u>				
	propagation delay	$V_{CC} = 2.7 V$	-	-	4.0	ns
		V_{CC} = 3.0 V to 3.6 V	0.5	1.8	3.2	ns
t _{PHL}	HIGH to LOW	nAn to nYn; see <u>Figure 5</u>				
	propagation delay	$V_{CC} = 2.7 V$	-	-	4.0	ns
		V_{CC} = 3.0 V to 3.6 V	0.5	1.7	3.2	ns
t _{PZH}	OFF-state to HIGH	nOE to nYn; see <u>Figure 6</u>				
	propagation delay	$V_{CC} = 2.7 V$	-	-	5.0	ns
		V_{CC} = 3.0 V to 3.6 V	1.0	2.3	4.0	ns
t _{PZL}	OFF-state to LOW	nOE to nYn; see <u>Figure 6</u>				
	propagation delay	$V_{CC} = 2.7 V$	-	-	5.3	ns
		V_{CC} = 3.0 V to 3.6 V	1.0	2.1	4.0	ns
t _{PHZ}	HIGH to OFF-state	nOE to nYn; see <u>Figure 6</u>				
	propagation delay	$V_{CC} = 2.7 V$	-	-	5.0	ns
		V_{CC} = 3.0 V to 3.6 V	1.0	3.2	4.5	ns
t _{PLZ}	LOW to OFF-state	nOE to nYn; see <u>Figure 6</u>				
	propagation delay	$V_{CC} = 2.7 V$	-	-	4.4	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	1.0	2.9	4.0	ns

[1] Typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

3.3 V 16-bit buffer/driver; 3-state

11. Waveforms



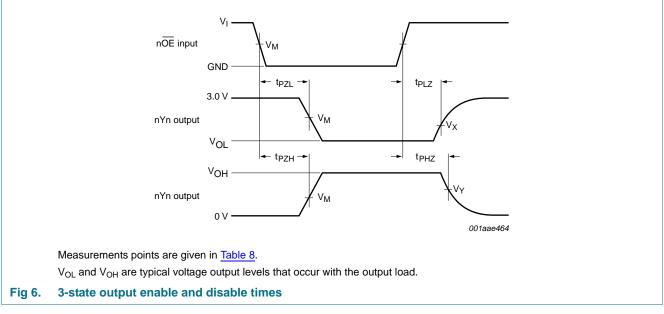


Table 8. Measurement points

Input	Output		
V _M	V _M	V _X	V _Y
1.5 V	1.5 V	V _{OL} + 0.3 V	$V_{OH} - 0.3 V$

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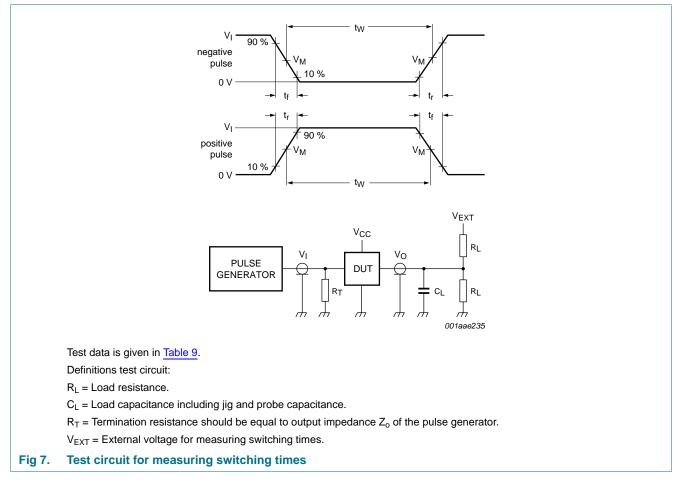


Table 9. Test data

Input				Load		V _{EXT}		
VI	f _i	t _W	t _r , t _f	CL	RL	t _{PHZ} , t _{PZH}	t _{PLZ} , t _{PZL}	t _{PLH} , t _{PHL}
2.7 V	\leq 10 MHz	500 ns	\leq 2.5 ns	50 pF	500 Ω	GND	6 V	open

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3.3 V 16-bit buffer/driver; 3-state

12. Package outline

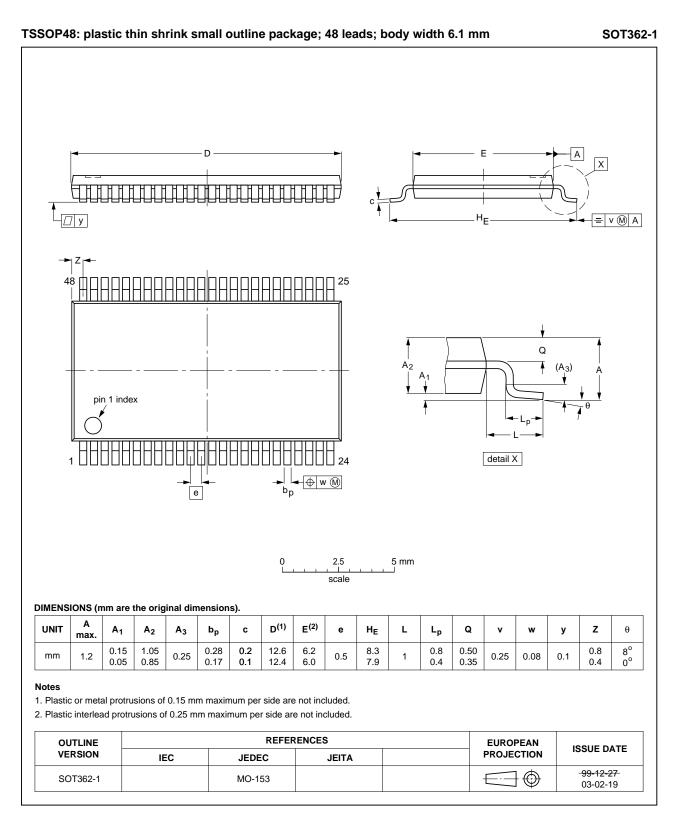
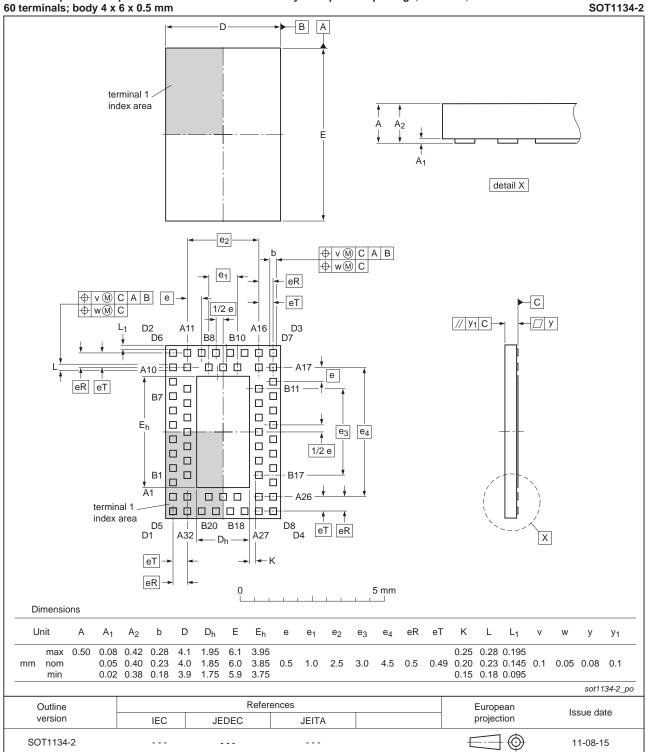


Fig 8. Package outline SOT362-1 (TSSOP48)

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HXQFN60: plastic compatible thermal enhanced extremely thin quad flat package; no leads; 60 terminals; body 4 x 6 x 0.5 mm

Fig 9. Package outline SOT1134-2 (HXQFN60)

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13. Abbreviations

Acronym BiCMOS DUT ESD	Description Bipolar Complementary Metal Oxide Semiconductor Device Under Test
DUT	Device Under Test
ESD	
	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVTN16244B v.5	20120402	Product data sheet	-	74LVTN16244B v.4
Modifications:	 For type nu 	mber 74LVTN16244BBX th	ne sot code has changed	to SOT1134-2.
74LVTN16244B v.4	20111122	Product data sheet	-	74LVTN16244B v.3
Modifications:	 Legal pages 	s updated.		
74LVTN16244B v.3	20110614	Product data sheet	-	74LVTN16244B v.2
74LVTN16244B v.2	20100323	Product data sheet	-	74LVTN16244B v.1
74LVTN16244B v.1	20090713	Product data sheet	-	-

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3.3 V 16-bit buffer/driver; 3-state

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